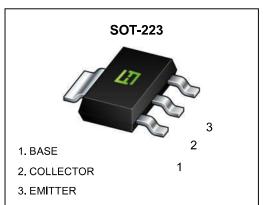


TRANSISTOR (NPN)

FEATURES

- For AF driver and output stages
- High collector current
- Low collector-emitter saturation voltage
- Complementary types: BCP51 ... BCP53 (PNP)



MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Symbol	Parameter	BCP54	BCP55	BCP56	Unit
V _{CBO}	Collector-Base Voltage	45	60	100	V
V _{CEO}	Collector-Emitter Voltage	45	60	80	V
V _{EBO}	Emitter-Base Voltage		5		V
lc	Collector Current -Continuous		1		А
I _{см}	Peak Pulse Collector Current	2		А	
I _B	Base Current-Continuous		100		mA
I _{ВМ}	Peak Pulse Base Current	200		mA	
Pc	Collector Power Dissipation	1.5		W	
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55~+150		°C	
$R_{ extsf{ heta}JA}$	Thermal Resistance Junction to Ambient		83.3		°C/W

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

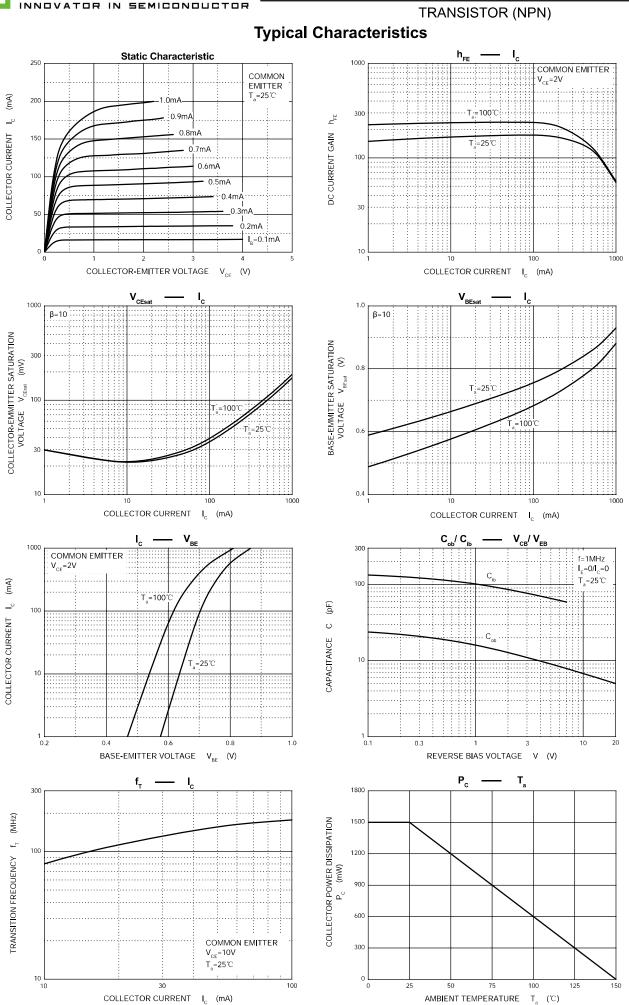
Parameter		Symbol	Test conditions	Min	Мах	Unit
Collector-base breakdown voltage	BCP54			45		
	BCP55	V _{(BR)CBO}	I _C = 0.1mA,I _E =0	60		V
	BCP56			100		
Collector-emitter breakdown voltage	BCP54			45		
	BCP55	V _{(BR)CEO}	$I_{\rm C}$ = 10mA, $I_{\rm B}$ =0	60		V
	BCP56			80		
Base-emitter breakdown voltage		V _{(BR)EBO}	I _E = 10μΑ,I _C =0	5		V
Collector cut-off current		I _{CBO}	V _{CB} = 30 V, I _E =0		100	nA
		h _{FE(1)}	V_{CE} = 2V, I _C =5mA	25		
DC current gain		h _{FE(2)}	V _{CE} = 2V, I _C =150m A	63	250	
		h _{FE(3)}	V_{CE} = 2V, I _C =500m A	25		
Collector-emitter saturation voltage		V _{CE(sat)}	I _C =500mA,I _B =50mA		0.5	V
Base-emitter voltage		V _{BE}	V _{CE} =2V, I _C =500m A		1	V
Transition frequency		fT	V _{CE} =10V,I _C =50mA,f=100MHz	100		MHz

CLASSIFICATION OF h_{FE(2)}

Rank	BCP54-10, BCP55-10, BCP56-10	BCP54-16, BCP55-16, BCP56-16		
Range	63-160	100-250		
Marking	BCP54-10, BCP55-10, BCP56-10	BCP54-16, BCP55-16, BCP56-16		



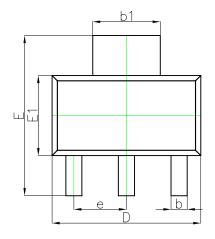
BCP54/55/56T1G

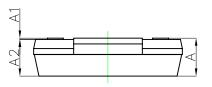


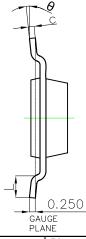


TRANSISTOR (NPN)

SOT-223 Package Outline Dimensions

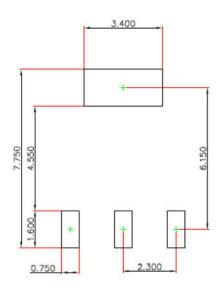






Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А		1.800		0.071	
A1	0.020	0.100	0.001	0.004	
A2	1.500	1.700	0.059	0.067	
b	0.660	0.840	0.026	0.033	
b1	2.900	3.100	0.114	0.122	
С	0.230	0.350	0.009	0.014	
D	6.300	6.700	0.248	0.264	
E	6.700	7.300	0.264	0.287	
E1	3.300	3.700	0.130	0.146	
е	2.300(BSC)	0.091	BSC)	
Ĺ	0.750		0.030		
θ	0°	10°	0°	10°	

SOT-223 Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

2.General tolerance:±0.050mm.

3. The pad layout is for reference purposes only.